

View Online at <https://aerobasegroup.com/nsn/5961-01-525-2762>

Inclosure Material:

Ceramic

Overall Length:

Between 0.240 inches and 0.250 inches

Overall Height:

Between 0.058 inches and 0.100 inches

Overall Width:

Between 0.165 inches and 0.175 inches

Mounting Facility Quantity:

6

Component Name And Quantity:

2 transistor

Mounting Method:

Slot

Semiconductor Material:

Silicon all semiconductor

Voltage Rating In Volts Per Characteristic:

75.0 collector to base voltage/static/emitter open all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

600.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

0.6 watts small-signal input power, common-emitter outside diameter all transistor

Product Name:

Semiconductor device, unitized, dual-transistor, npn, silicon

Terminal Type And Quantity:

6 bonding pad

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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